

TD817X2H Series

DC Input High Temperature Operation , Photo Transistor Optocoupler

Description

The TD817X2H series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon planar phototransistor detector in a plastic DIP4 package with different lead forming options. With the robust coplanar double mold structure, TD817X2H series provide the most stable isolation feature.

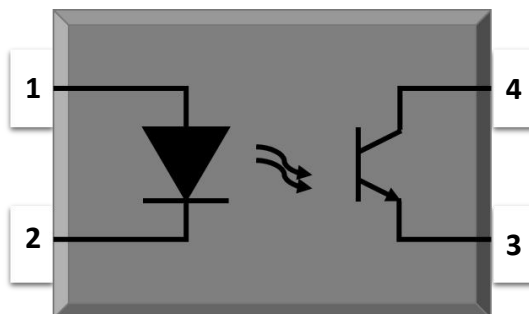
Features

- High isolation 5000 VRMS
- CTR flexibility available see order information
- DC input with transistor output
- Operating temperature range - 55 °C to 125 °C
- RoHS & REACH Compliance
- MSL class 1
- Halogen free (Optional)
- Regulatory Approvals
 - UL - UL1577
 - VDE - EN60747-5-5(VDE0884-5)
 - CQC - GB4943.1, GB8898
 - cUL- CSA Component Acceptance Service Notice No. 5A

Applications

- Switch mode power supplies
- Programmable controllers
- Household appliances
- Office equipment

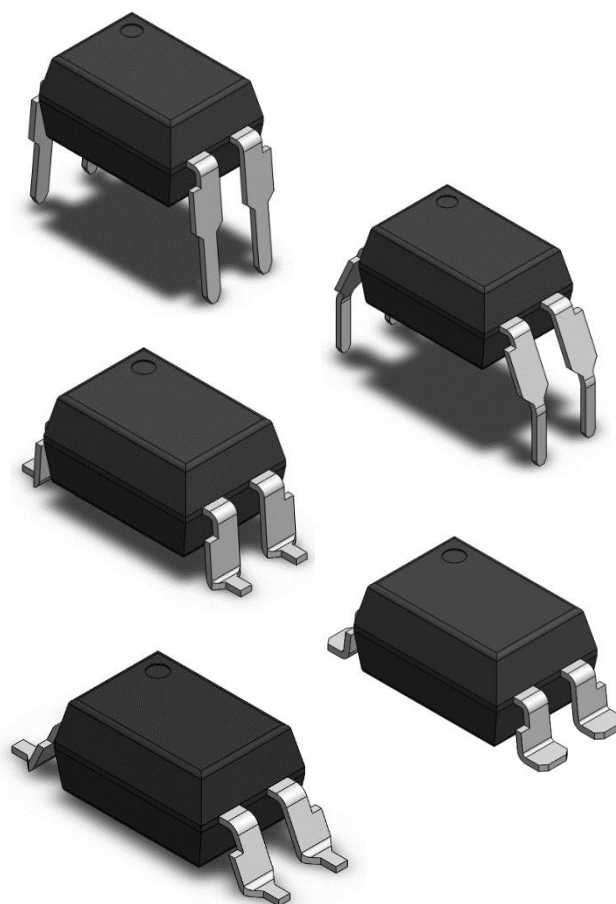
SCHEMATIC



PIN DEFINITION

1. Anode
2. Cathode
3. Emitter
4. Collector

PACKAGE OUTLINE



**DC Input High Temperature Operation ,
Photo Transistor Optocoupler****ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT	NOTE
INPUT				
Forward Current	I_F	60	mA	
Peak Forward Current	I_{FP}	1	A	1
Reverse Voltage	V_R	6	V	
Input Power Dissipation	P_I	100	mW	
OUTPUT				
Collector - Emitter Voltage	V_{CEO}	35	V	
Emitter - Collector Voltage	V_{ECO}	6	V	
Collector Current	I_C	50	mA	
Output Power Dissipation	P_O	150	mW	
COMMON				
Total Power Dissipation	P_{tot}	200	mW	
Isolation Voltage	V_{iso}	5000	Vrms	2
Operating Temperature	T_{opr}	-55~125	°C	
Storage Temperature	T_{stg}	-55~150	°C	
Soldering Temperature	T_{sol}	260	°C	

Note 1. 100μs pulse, 100Hz frequency

Note 2. AC For 1 Minute, R.H. = 40 ~ 60%

**DC Input High Temperature Operation ,
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ELECTRICAL OPTICAL CHARACTERISTICS at Ta=25°C							
PARAMETER	SYMBOL	MIN	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
INPUT							
Forward Voltage	V _F	-	1.24	1.4	V	IF=10mA	
Reverse Current	I _R	-	-	10	μA	VR=6V	
Input Capacitance	C _{in}	-	10	-	pF	V=0, f=1kHz	
OUTPUT							
Collector Dark Current	I _{CEO}	-	-	100	nA	VCE=20V, IF=0	
Collector-Emitter Breakdown Voltage	BV _{CEO}	35	-	-	V	IC=0.1mA, IF=0	
Emitter-Collector Breakdown Voltage	BV _{ECO}	6	-	-	V	IE=0.1mA, IF=0	
TRANSFER CHARACTERISTICS							
Current Transfer Ratio	TD817A2H	CTR	80	-	160	IF=5mA, VCE=5V	
	TD817B2H		130	-	260		
	TD817C2H		200	-	400		
	TD817D2H		300	-	600		
	TD817A2H		32	-	-	IF=1mA, VCE=5V	
	TD817B2H		52	-	-		
	TD817C2H		80	-	-		
	TD817D2H		120	-	-		
Collector-Emitter Saturation Voltage	V _{CE(sat)}	-	0.06	0.2	V	IF=20mA, IC=1mA	
Isolation Resistance	R _{ISO}	10 ¹²	10 ¹⁴	-	Ω	DC500V, 40 ~ 60% R.H.	
Floating Capacitance	C _{IO}	-	0.4	1	pF	V=0, f=1MHz	
Response Time (Rise)	t _r	-	6	18	μs	VCE=2V, IC=2mA RL=100Ω	3
Response Time (Fall)	t _f	-	8	18	μs		3
Cut-off Frequency	f _c	-	80	-	kHz	VCE=2V, IC=2mA RL=100Ω,-3dB	4

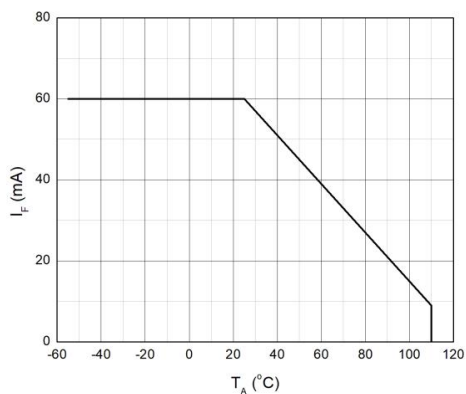
Note 3. Fig.12&13

Note 4. Fig.14

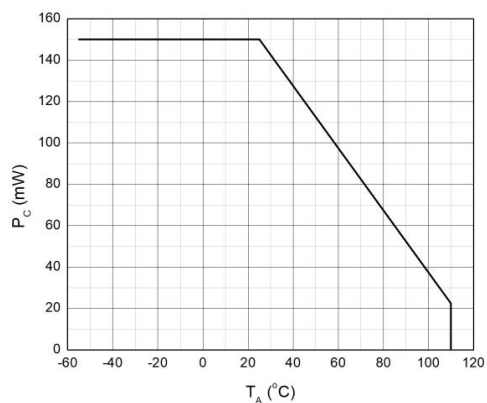
DC Input High Temperature Operation , Photo Transistor Optocoupler

CHARACTERISTIC CURVES

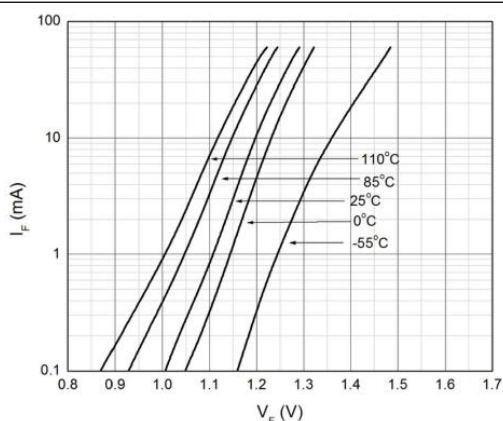
**Fig.1 Forward Current
vs. Ambient Temperature**



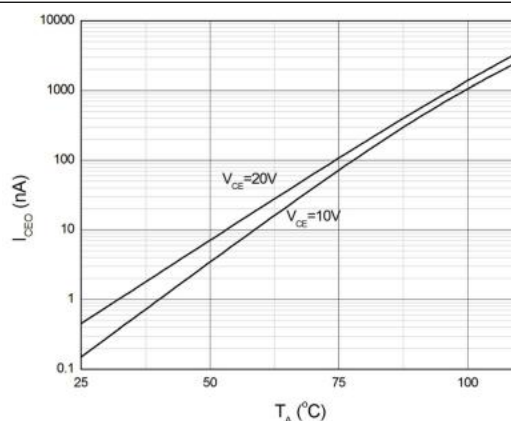
**Fig.2 Collector Power Dissipation
vs. Ambient Temperature**



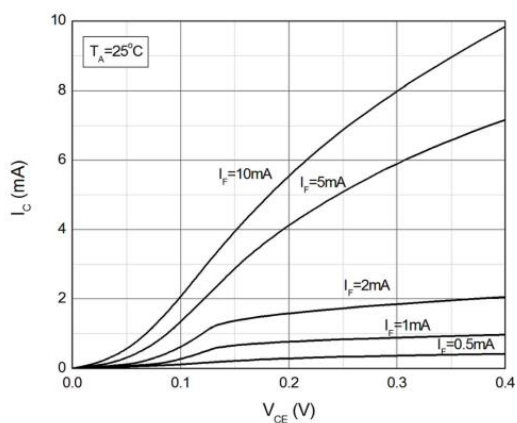
**Fig.3 Forward Current
vs. Forward Voltage**



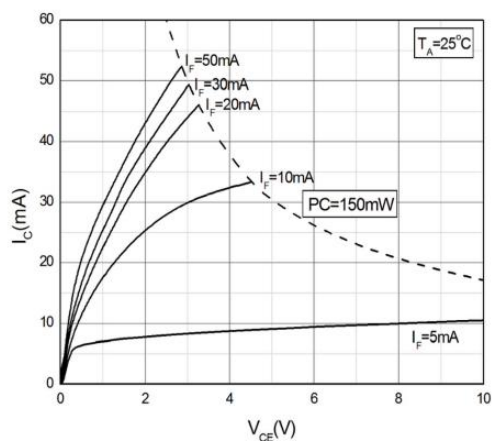
**Fig.4 Collector Dark Current
vs. Ambient Temperature**



**Fig.5 Collector Current
vs. Collector-emitter Voltage**



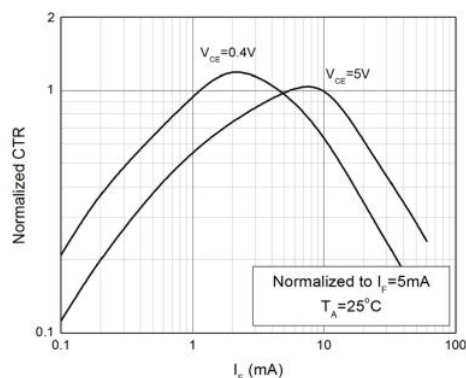
**Fig.6 Collector Current
vs. Collector-emitter Voltage**



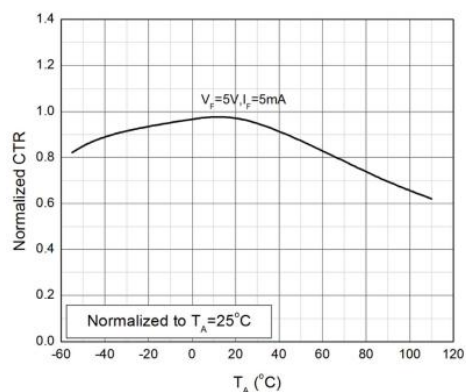
DC Input High Temperature Operation , Photo Transistor Optocoupler

CHARACTERISTIC CURVES

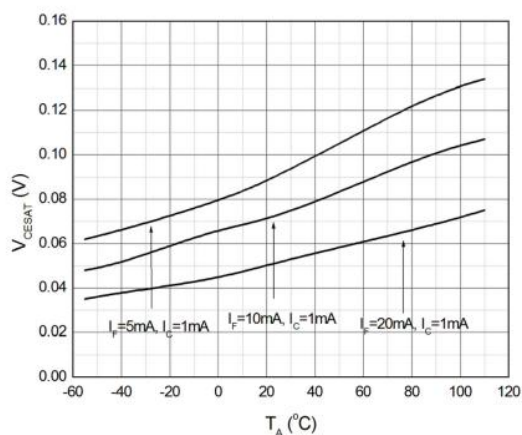
**Fig.7 Normalized Current Transfer Ratio
vs. Forward Current**



**Fig.8 Normalized Current Transfer Ratio
vs. Ambient Temperature**



**Fig.9 Collector-emitter Saturation Voltage
vs. Ambient Temperature**



**Fig.10 Switching Time
vs. Load Resistance**

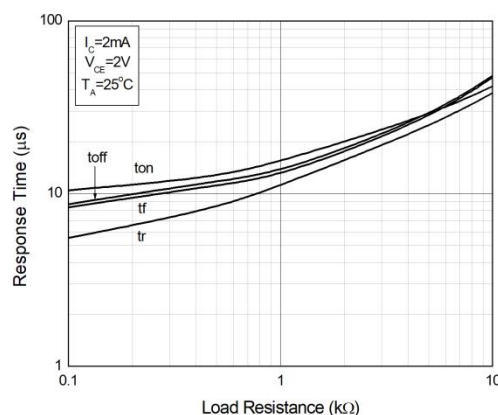
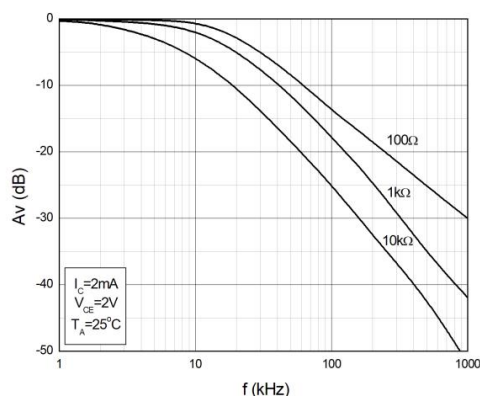


Fig.11 Frequency Response



DC Input High Temperature Operation , Photo Transistor Optocoupler

TEST CIRCUITS

Fig.12 Test Circuits of Response Time

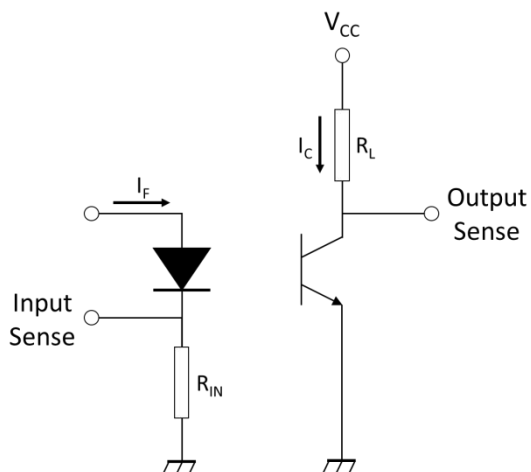


Fig.13 Curves of Response Time

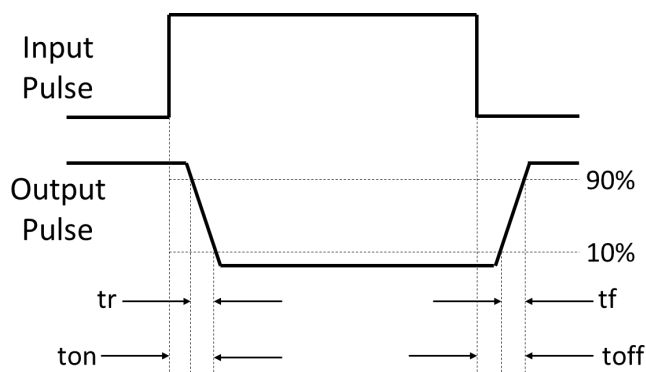
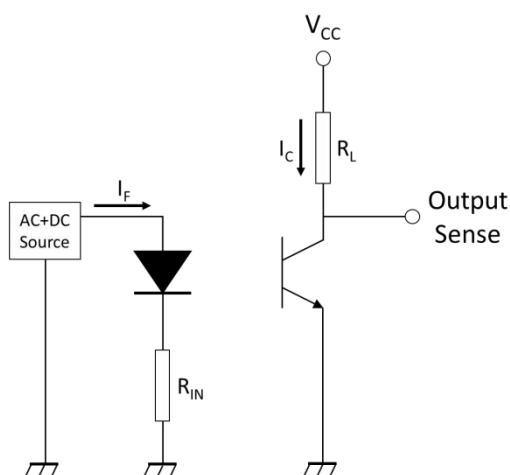


Fig.14 Test Circuits of Frequency Response

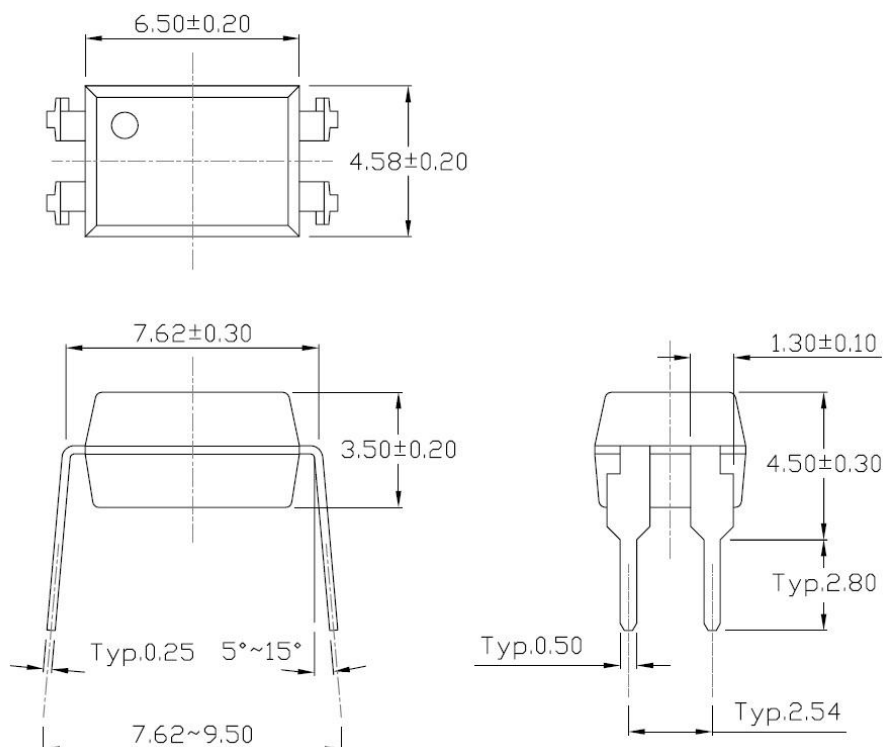


TD817X2H Series

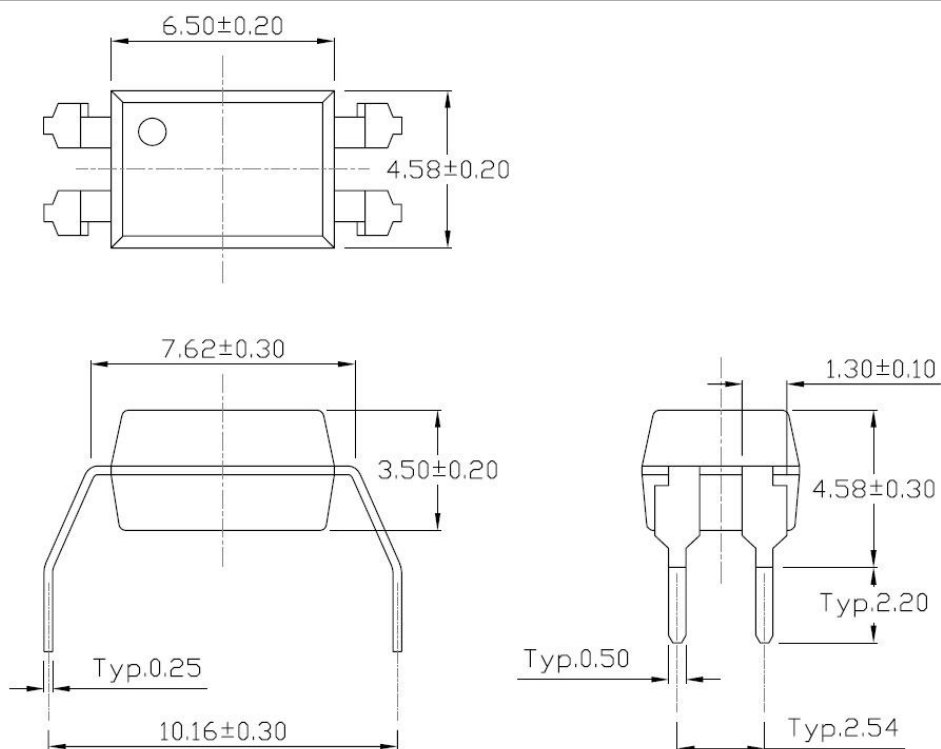
DC Input High Temperature Operation , Photo Transistor Optocoupler

PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)

Standard DIP – Through Hole (DIP Type)



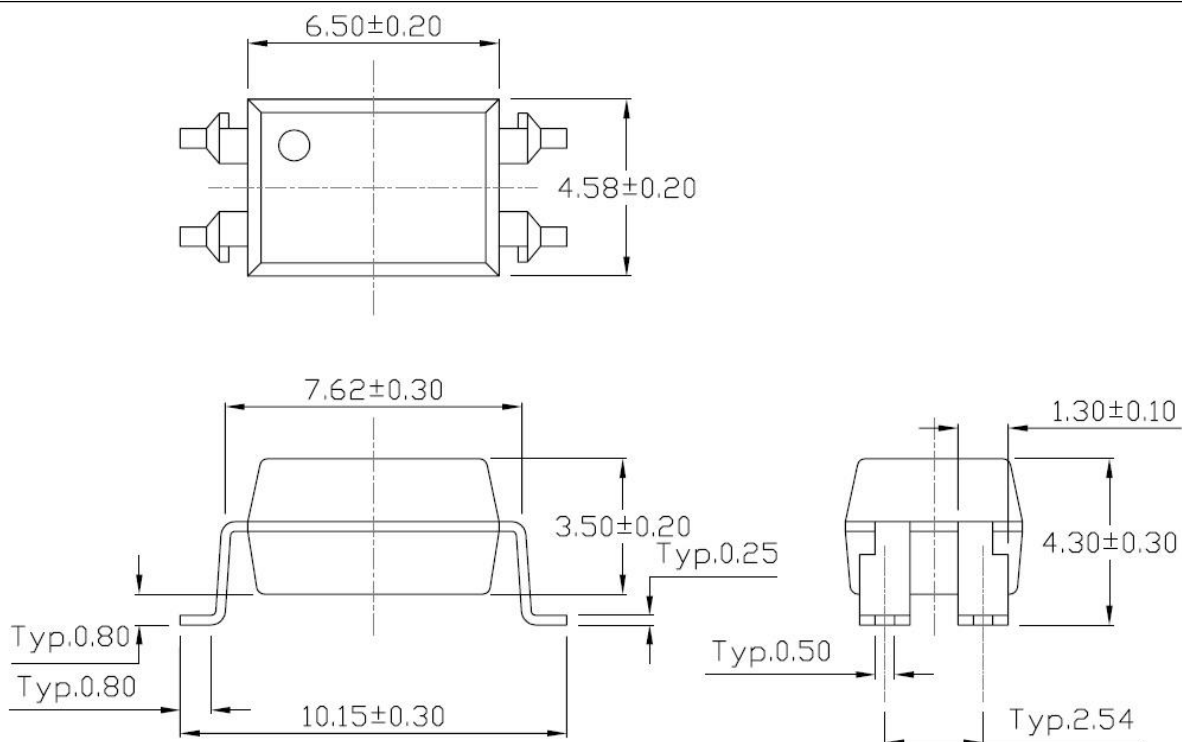
Gullwing (400mil) Lead Forming – Through Hole (M Type)



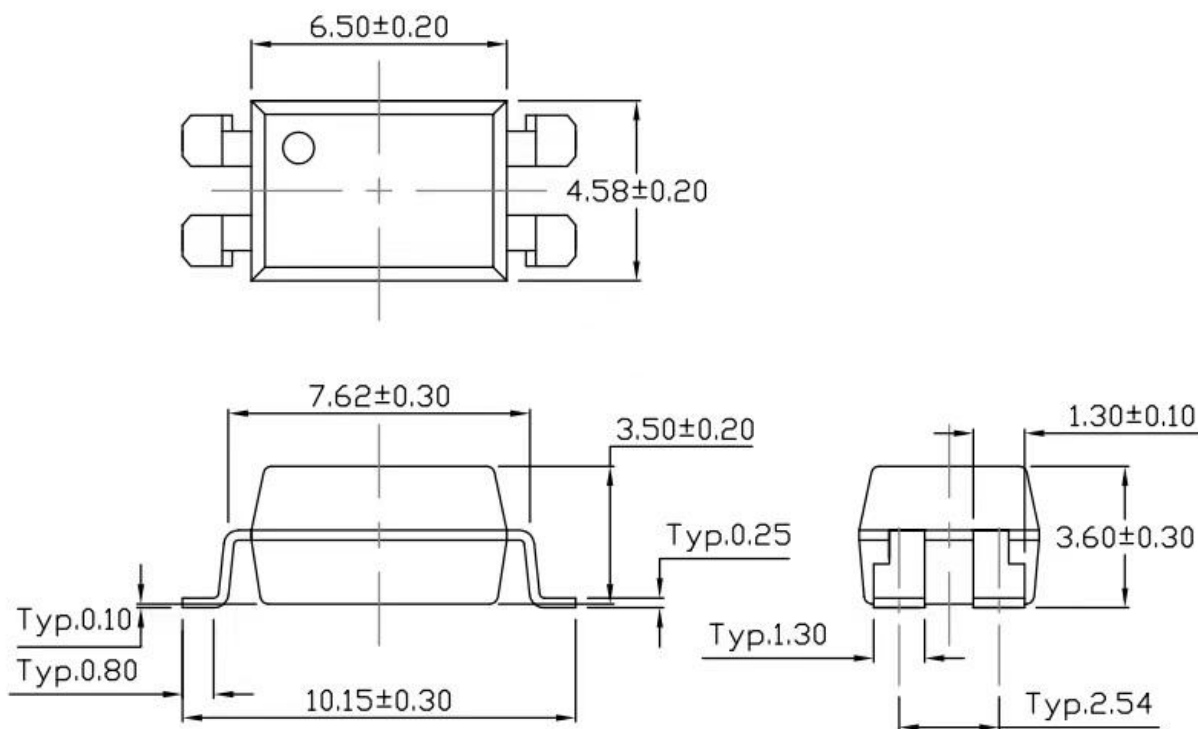
DC Input High Temperature Operation , Photo Transistor Optocoupler

PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)

Surface Mount Lead Forming (S Type)



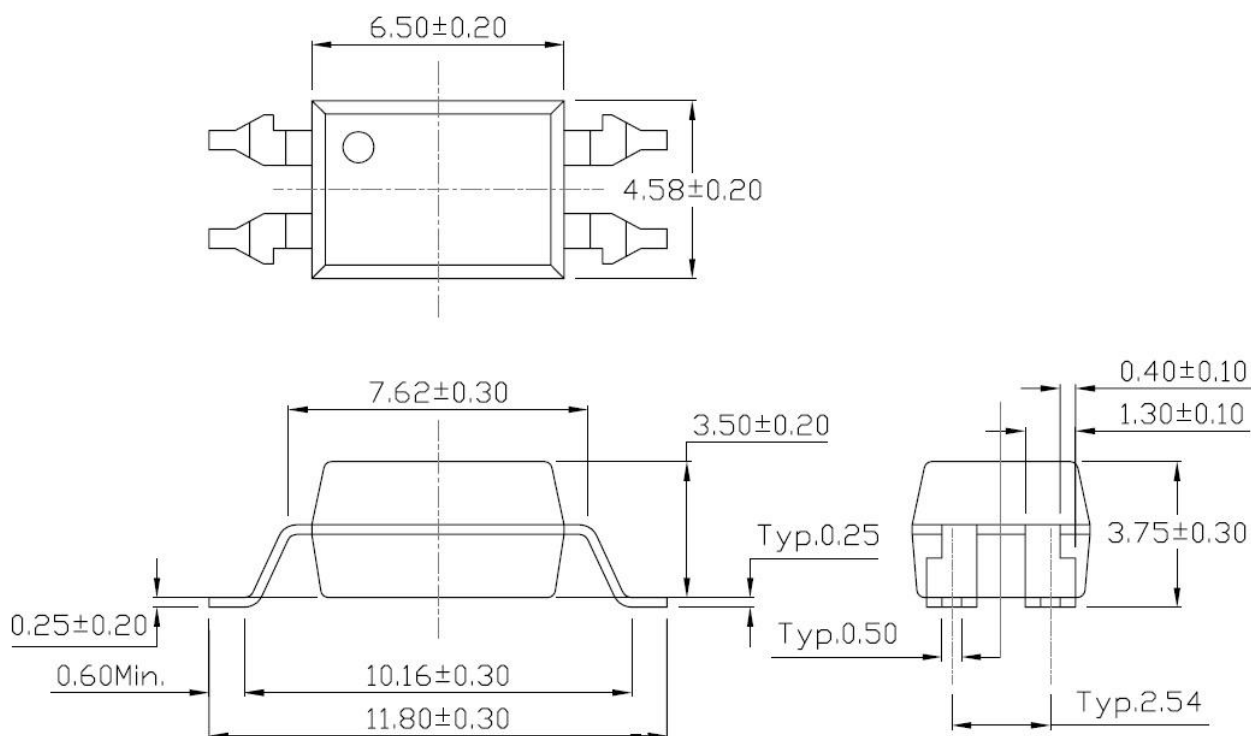
Surface Mount (Low Profile) Lead Forming (SL Type)



DC Input High Temperature Operation , Photo Transistor Optocoupler

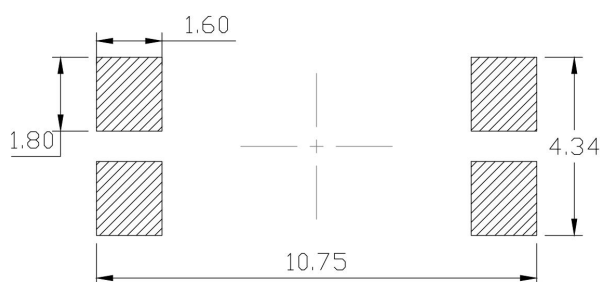
PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)

Surface Mount (Gullwing) Lead Forming (SLM Type)

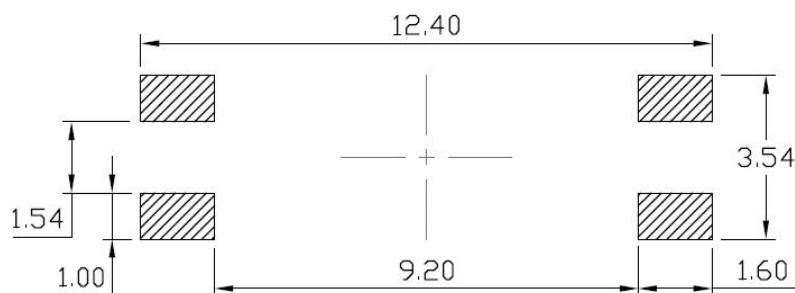


RECOMMENDED SOLDER MASK (Dimensions in mm unless otherwise stated)

Surface Mount Lead Forming & Surface Mount (Low Profile) Lead Forming



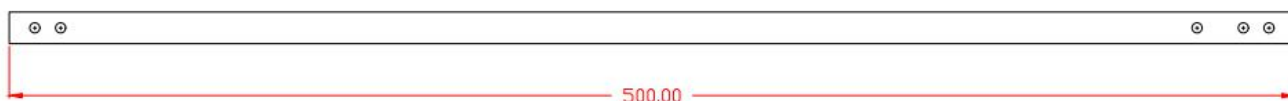
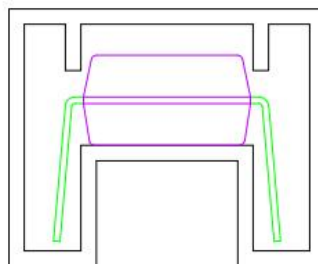
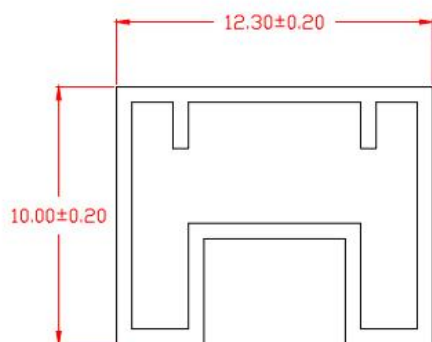
Surface Mount (Gullwing) Lead Forming



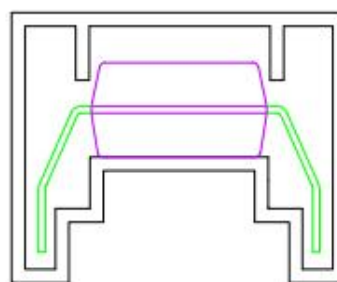
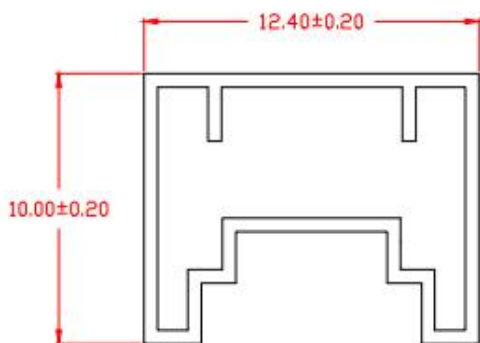
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TUBE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Standard DIP



Standard M



TD817X2H Series

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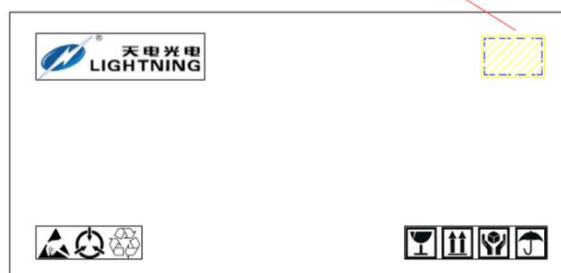
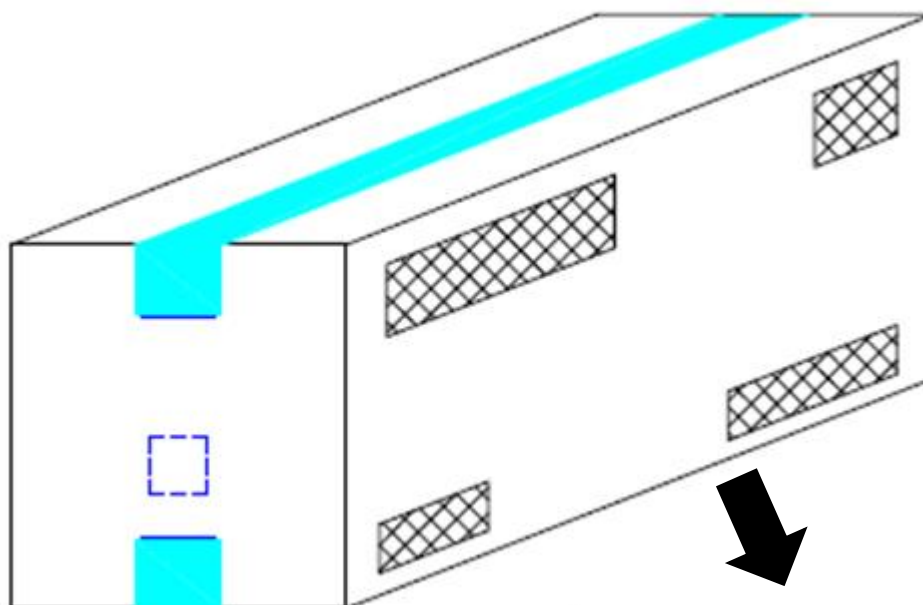
BOX SPECIFICATIONS (Tube Type)

Inner Box



- L x W x H = 52.5cm x 10.7cm x 4.7cm

Outer Box

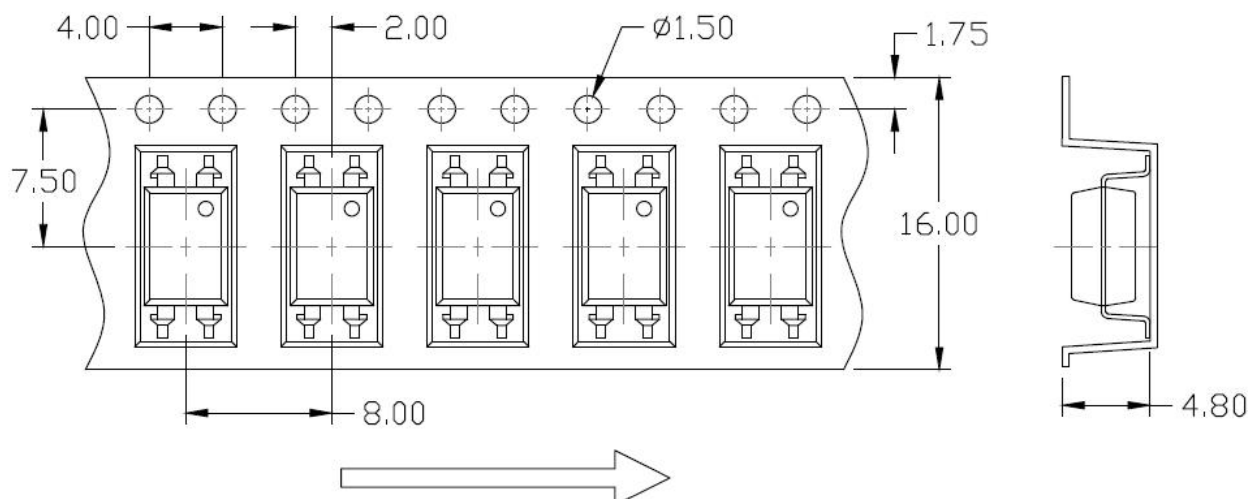


- L x W x H = 53.5cm x 23.5cm x 25.5cm

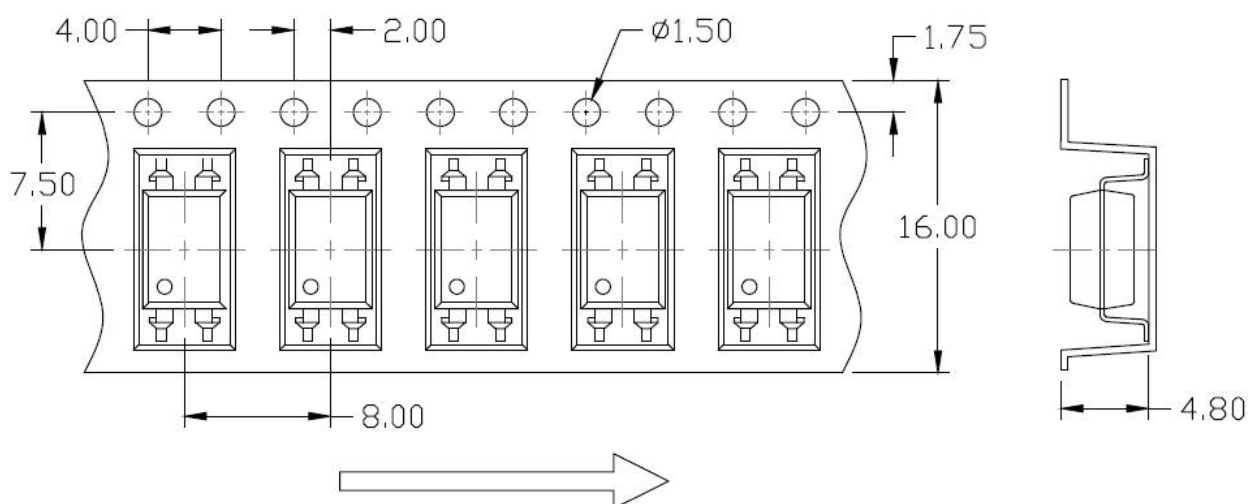
DC Input High Temperature Operation , Photo Transistor Optocoupler

CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option S(T1)



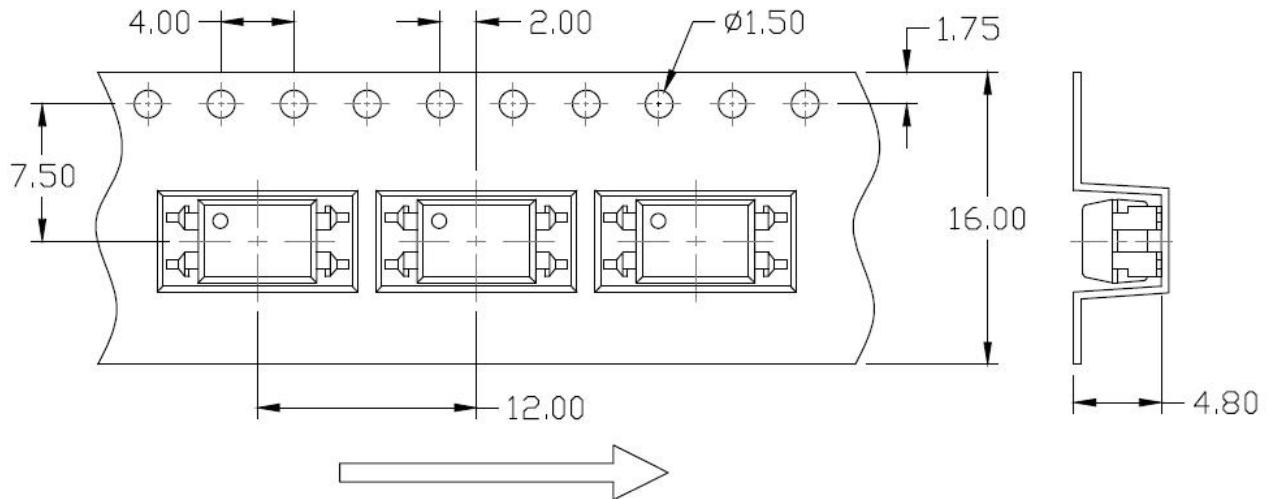
Option S(T2)



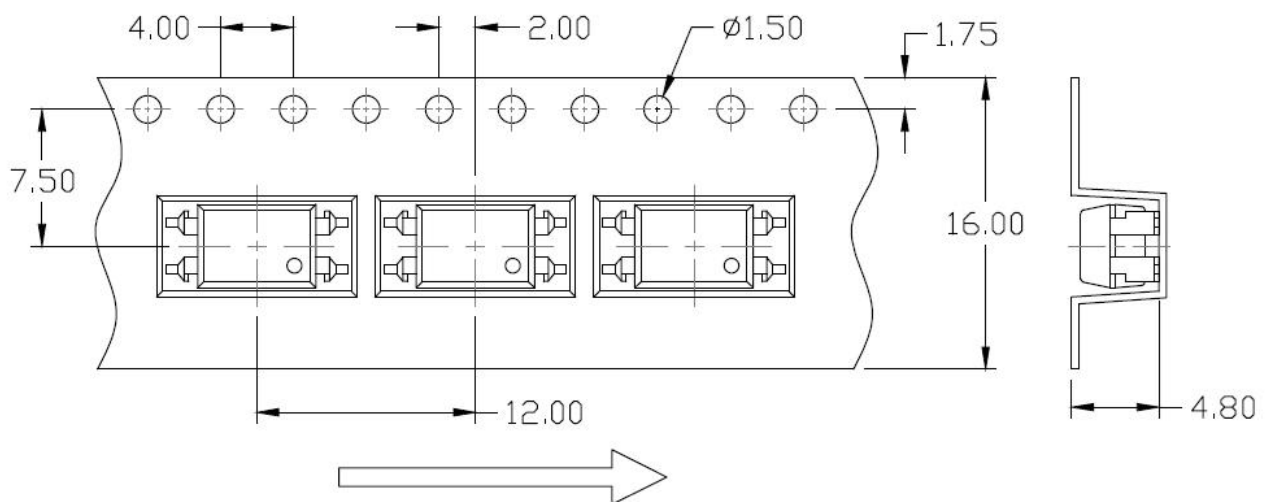
DC Input High Temperature Operation , Photo Transistor Optocoupler

CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option S(T3)



Option S(T4)



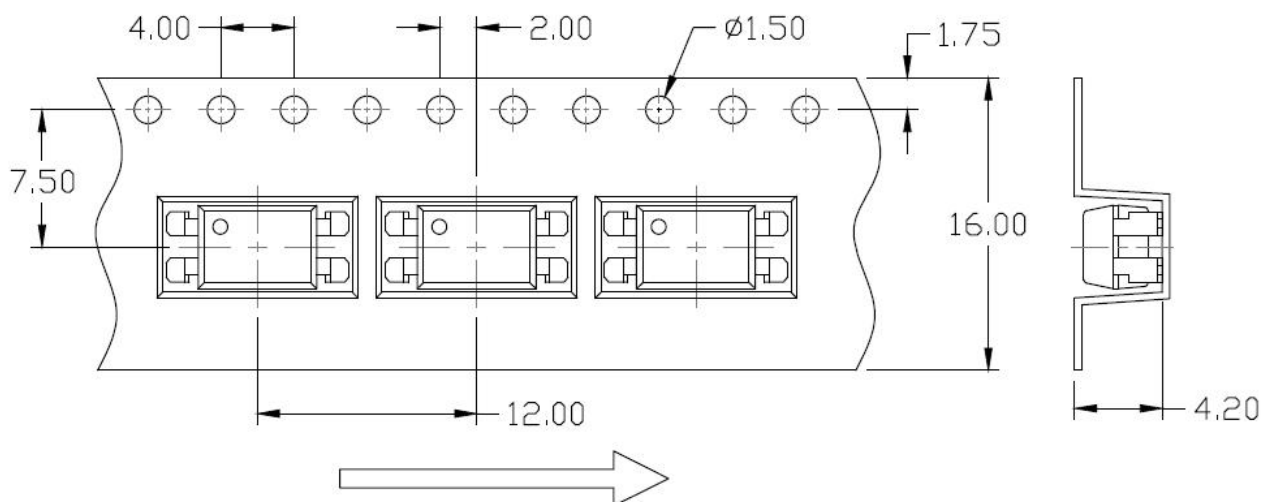


DC Input High Temperature Operation , Photo Transistor Optocoupler

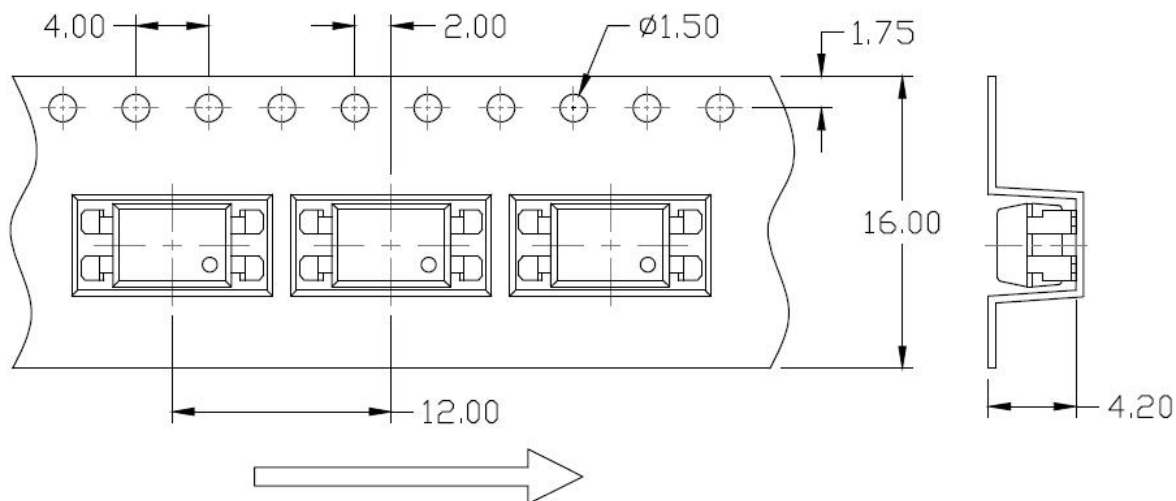
DC Input High Temperature Operation , Photo Transistor Optocoupler

CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option SL(T3)



Option SL(T4)

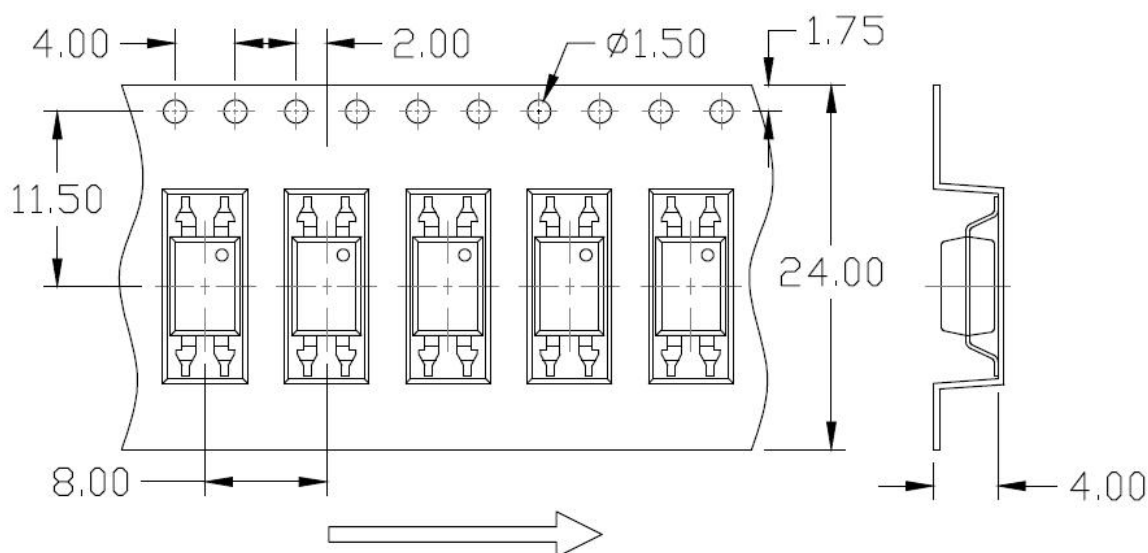


TD817X2H Series

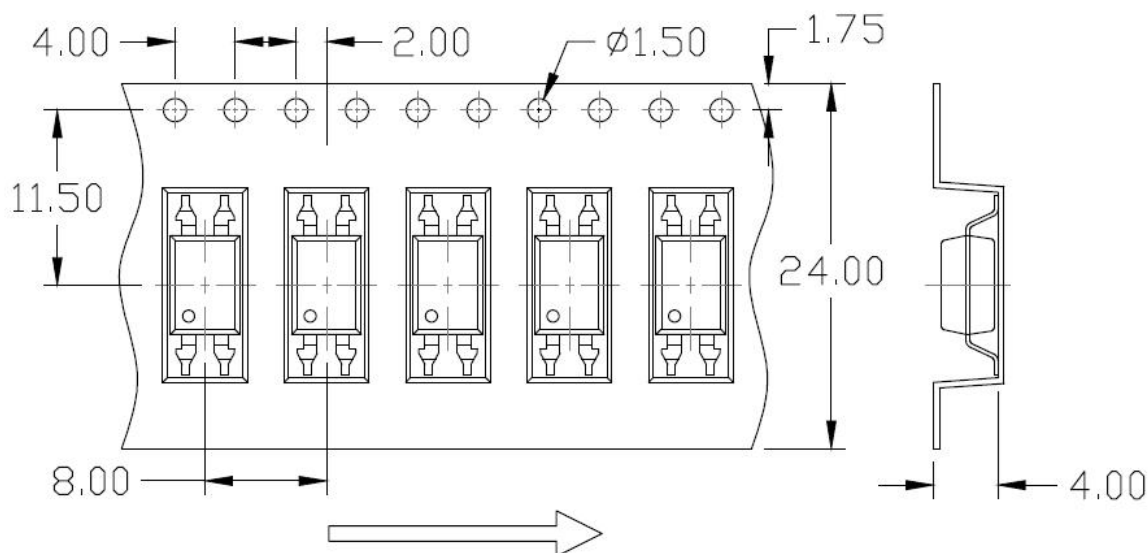
DC Input High Temperature Operation , Photo Transistor Optocoupler

CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option SLM(T1)



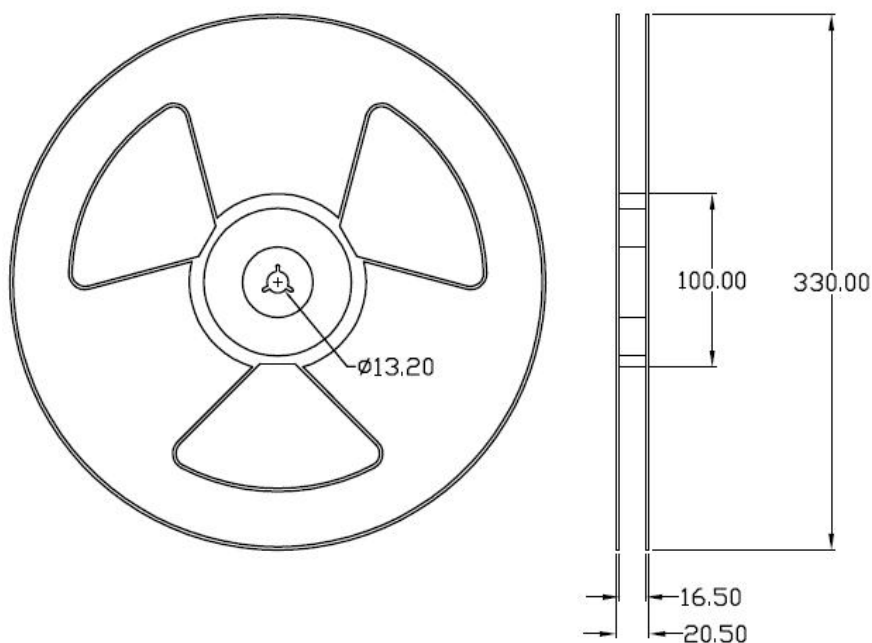
Option SLM(T2)



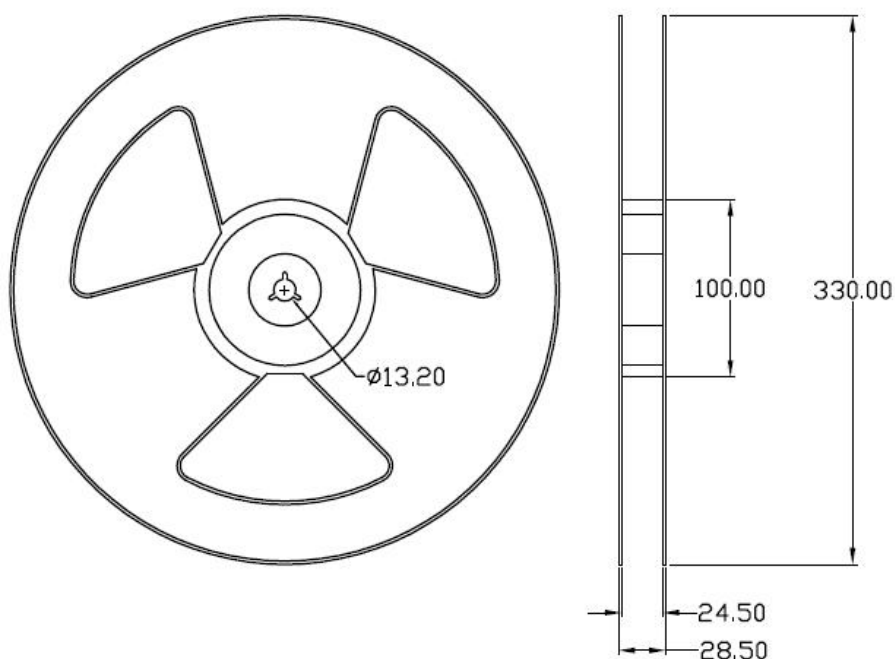
DC Input High Temperature Operation , Photo Transistor Optocoupler

REEL SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option S & Option SL

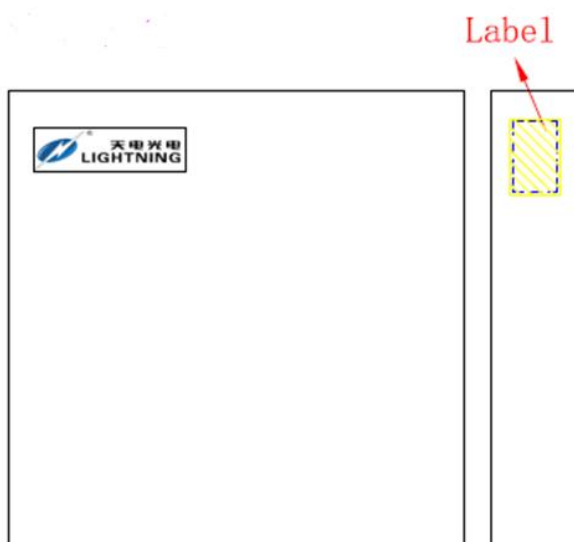


Option SLM



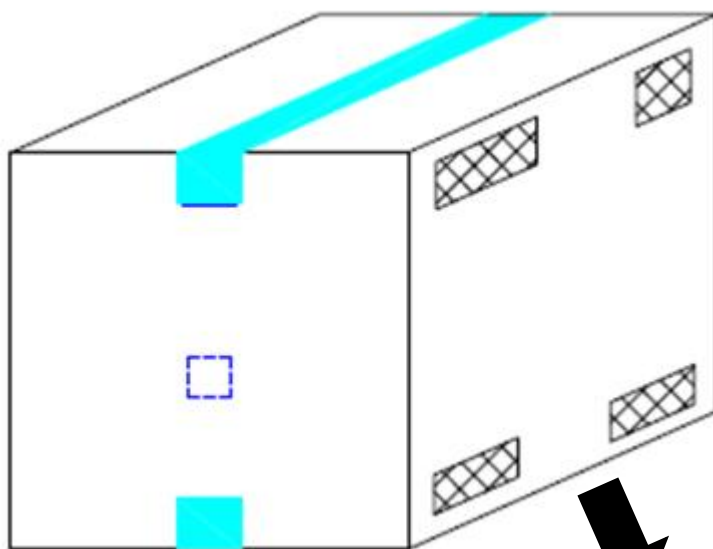
BOX SPECIFICATIONS (Reel Type)

Inner Box

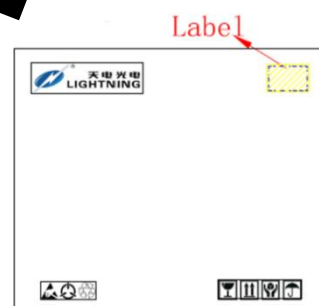


- L x W x H = 36cm x 36cm x 6.9cm

Outer Box



- L x W x H = 45cm x 38cm x 38cm

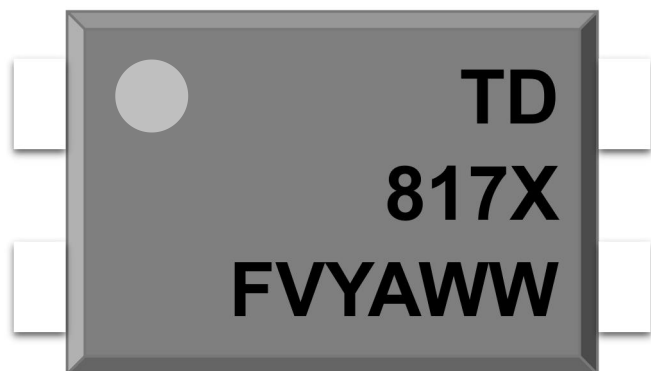




DC Input High Temperature Operation , Photo Transistor Optocoupler

ORDERING AND MARKING INFORMATION

MARKING INFORMATION



TD : Company Abbr.
817 : Part Number
X : CTR Rank
F : Leadframe Option
V : VDE Option
Y : Fiscal Year
A : Manufacturing Code
WW : Work Week

ORDERING INFORMATION

TD817X2H(Y)(Z)-FGV

TD – Company Abbr.
 817 – Part Number
 X2H – Rank (A2H/B2H/C2H/D2H)
 Y – Lead Form Option (M/S/SL/SLM/None)
 Z – Tape and Reel Option (T1/T2/T3/T4)
 F – Leadframe Option (F:Iron, None:Copper)
 G – Green
 V – VDE Option (V or None)

LABEL INFORMATION



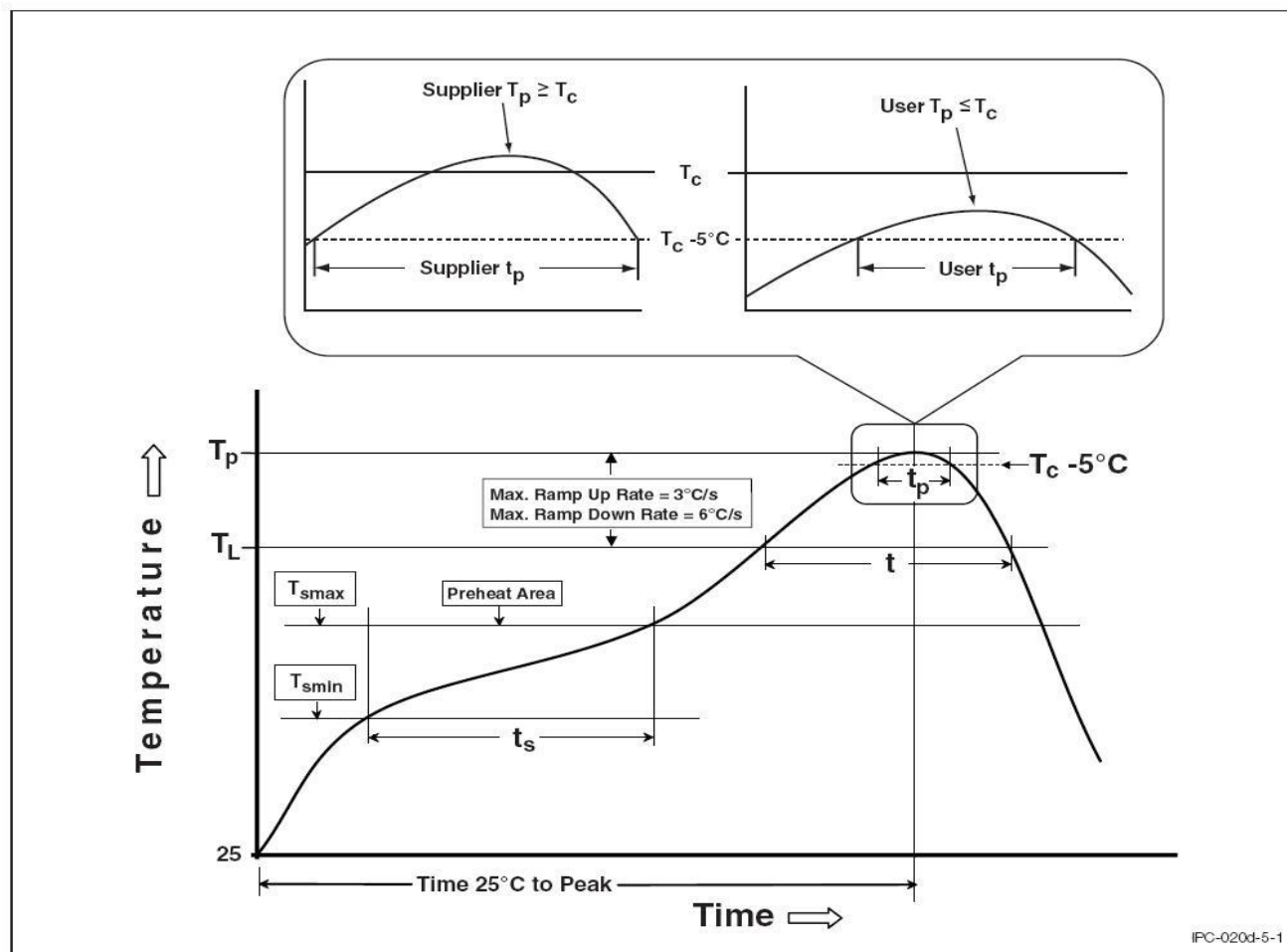
Packing Quantity

Option	Quantity	Quantity – Inner box	Quantity – Outer box
None	100 Units/Tube	32 Tubes/Inner box	10 Inner box/Outer box = 32k Units
M	100 Units/Tube	32 Tubes/Inner box	10 Inner box/Outer box = 32k Units
S(T1)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
S(T2)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
S(T3)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
S(T4)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
SL(T1)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
SL(T2)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
SL(T3)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
SL(T4)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
SLM(T1)	1500 Units/Reel	2 Reels/Inner box	5 Inner box/Outer box = 15k Units
SLM(T2)	1500 Units/Reel	2 Reels/Inner box	5 Inner box/Outer box = 15k Units

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REFLOW INFORMATION

REFLOW PROFILE

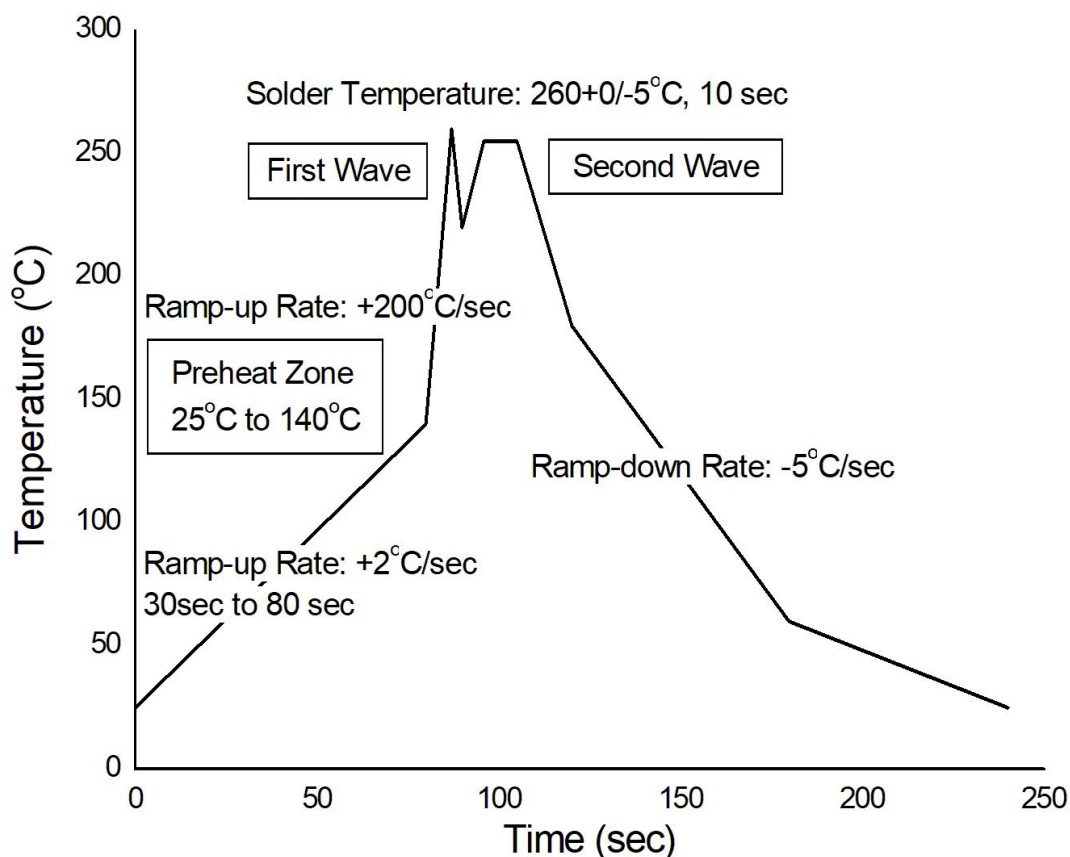


Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (T _{min})	100	150°C
Temperature Max. (T _{max})	150	200°C
Time (t _s) from (T _{min} to T _{max})	60-120 seconds	60-120 seconds
Ramp-up Rate (t _L to t _P)	3°C/second max.	3°C/second max.
Liquidous Temperature (T _L)	183°C	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds	60 – 150 seconds
Peak Body Package Temperature	235°C +0°C / -5°C	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	20 seconds	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max	6°C/second max
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

**DC Input High Temperature Operation ,
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TEMPERATURE PROFILE OF SOLDERING

WAVE SOLDERING (JESD22-A111 COMPLIANT)



HAND SOLDERING BY SOLDERING IRON

Soldering Temperature	380+0/-5°C
Soldering Time	3 sec max.

- One time soldering is recommended for all soldering method.
- Do not solder more than three times for IR reflow soldering.



***DC Input High Temperature Operation ,
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DISCLAIMER

- LIGHTNING is continually improving the quality, reliability, function and design. LIGHTNING reserves the right to make changes without further notices.
- The characteristic curves shown in this datasheet are representing typical performance which are not guaranteed.
- LIGHTNING makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, LIGHTNING disclaims (a) any and all liability arising out of the application or use of any product, (b) any and all liability, including without limitation special, consequential or incidental damages, and (c) any and all implied warranties, including warranties of fitness for particular
- The products shown in this publication are designed for the general use in electronic applications such as office automation, equipment, communications devices, audio/visual equipment, electrical application and instrumentation purpose, non-infringement and merchantability.
- This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or lifesaving applications or any other application which can result in human injury or death.
- Please contact LIGHTNING sales agent for special application request.
- Immerge unit's body in solder paste is not recommended.
- Parameters provided in datasheets may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated in each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify LIGHTNING's terms and conditions of purchase, including but not limited to the warranty expressed therein.